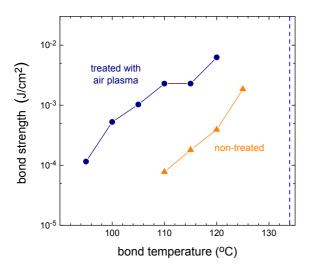
## **Supplementary Information**

## Injection molded nanofluidic chips: Fabrication method and functional tests using single-molecule DNA experiments†

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**Fig. S 1** Bond strength with respect to bond temperature. Pairs of flat injection molded discs in Topas 5013 were bonded in a hydraulic press for 10 min at a piston force of 15kN. The bond strength  $\gamma = 3Et_s^3t_b^2/(32L^4)$  was measured using a razor blade test, <sup>1</sup> for disc pairs that were either treated or non-treated with the air plasma as described in the main text. Here, E=3.2 GPa is the Topas 5013 modulus of elasticity,  $t_s=2$  mm the thickness of a single disc,  $t_b=0.25$  mm thickness of the razor blade, and L is the length of the delaminated region. Solid lines guide the eye, whereas the vertical dashed line indicates  $T_g=134^{\circ}\text{C}$  of Topas 5013. Note semi-log scale.

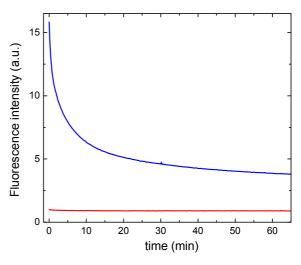


Fig. S 2 Autofluorescence intensity of nanochannel array area measured as a function of time under continuous illumination with metal halide lamp at 200 W output power. The same fluorescence microscopy setup with FITC filter cube (excitation: 465-495 nm, dichroic mirror: 505 nm, emission: 515-555 nm, Nikon) was used as for DNA experiments described in the main text. (Upper trace) Measurements taken for injection molded Topas 5013 chip sealed with  $150\mu$ m thick Topas 6013 foil. (Lower trace) Measurements taken for Si/SiO<sub>2</sub> chip sealed with  $550\mu$ m thick Borofloat glass lid.

## References

1 W. P. Maszara, G. Goetz, A. Caviglia and J. B. McKitterick, J. Appl. Phys., 1988, 64, 4943–4950.

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